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捷多邦，专业PCB打样工厂，24小时加急出货

急出货

KODENSHI

## Photointerrupters(Reflective)

**SG - 2BC**

The SG - 2BC reflective sensor combines a GaAs IRED with a high - sensitivity phototransistor in a super - mini (4 ) ceramic package, reducing installation space.

### FEATURES

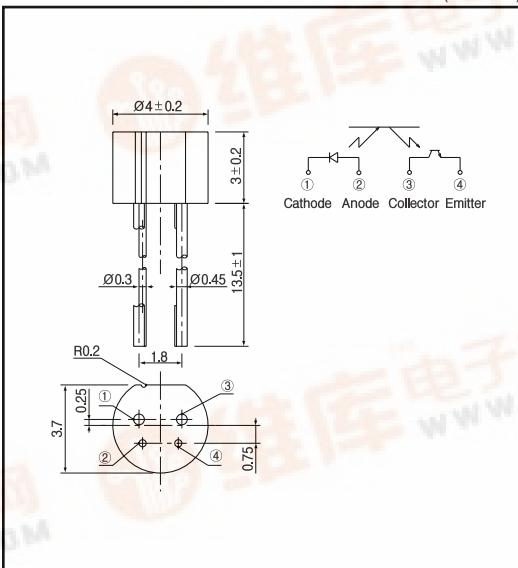
- Compact ( $\varnothing 4\text{mm}$ )
- High performance
- High - speed response
- Easy to mount on P.C.B.
- Widely applicable

### APPLICATIONS

- Timing sensors
- Edge sensors
- Micro floppy disk drives
- Level sensors of liquid

### DIMENSIONS

(Unit : mm)



### MAXIMUM RATINGS

(Ta=25 °C)

| Item            | Symbol           | Rating     | Unit |
|-----------------|------------------|------------|------|
| Input           | P <sub>d</sub>   | 75         | mW   |
|                 | V <sub>R</sub>   | 5          | V    |
|                 | I <sub>F</sub>   | 50         | mA   |
|                 | I <sub>FP</sub>  | 1          | A    |
| Output          | P <sub>C</sub>   | 75         | mW   |
|                 | I <sub>C</sub>   | 20         | mA   |
|                 | V <sub>CEO</sub> | 30         | V    |
|                 | V <sub>ECD</sub> | 3          | V    |
| Operating temp. | To <sub>pr</sub> | - 20 + 90  |      |
| Storage temp.   | T <sub>stg</sub> | - 30 + 100 |      |
| Soldering temp. | T <sub>sol</sub> | 260        |      |

\*1.t w 100 μsec.period :T=10msec.

\*2. For MAX. 5 seconds at the position of 2mm from the package

### ELECTRO-OPTICAL CHARACTERISTICS

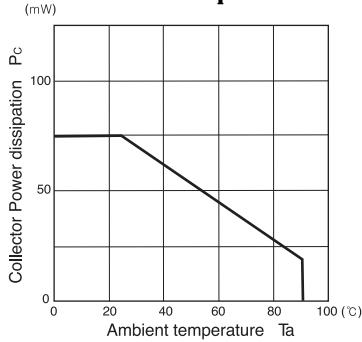
(Ta=25 °C)

| Item             | Symbol            | Conditions                       | Min. | Typ. | Max. | Unit. |
|------------------|-------------------|----------------------------------|------|------|------|-------|
| Input            | V <sub>F</sub>    | I = 4mA                          |      |      | 1.2  | V     |
|                  | I <sub>R</sub>    | V <sub>R</sub> =5V               |      |      | 10   | μA    |
|                  | C <sub>t</sub>    | V=0V,f=1KHz                      |      | 25   |      | pF    |
|                  | λ <sub>p</sub>    |                                  |      | 940  |      | nm    |
| Output           | I <sub>CEO</sub>  | V <sub>CE</sub> =10V             |      |      | 0.1  | μA    |
|                  | I <sub>L</sub>    | V <sub>CE</sub> =2V,I=4mA        |      | 100  |      | μA    |
| Switching speeds | I <sub>CEO0</sub> | V <sub>CE</sub> =2V,I=4mA        |      |      | 0.1  | μA    |
|                  | t <sub>r</sub>    | V <sub>CC</sub> =2V,b=100μA,R=1k |      | 30   |      | μsec. |
|                  | t <sub>f</sub>    |                                  |      | 30   |      | μsec. |

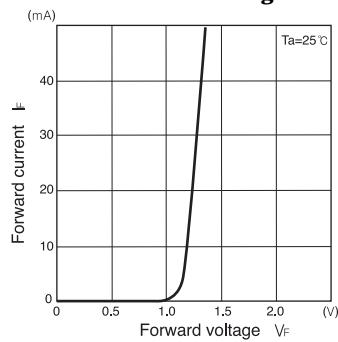
## Photo interrupters(Reflective)

SG - 2BC

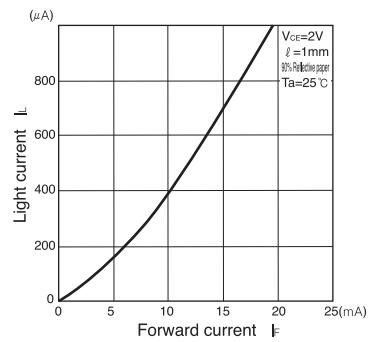
**Collector power dissipation Vs.  
Ambient temperature**



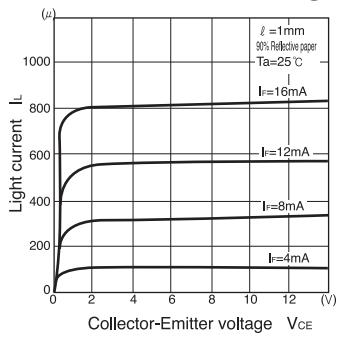
**Forward current Vs.  
Forward voltage**



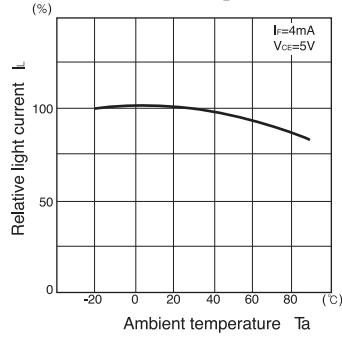
**Light current Vs.  
Forward current**



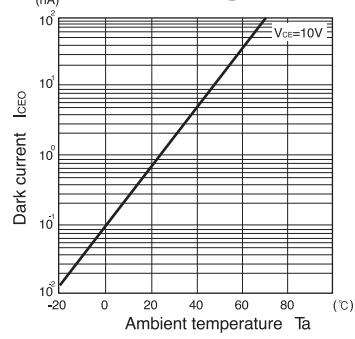
**Light current Vs.  
Collector-Emitter voltage**



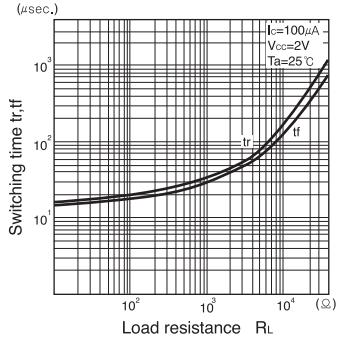
**Relative light current Vs.  
Ambient temperature**



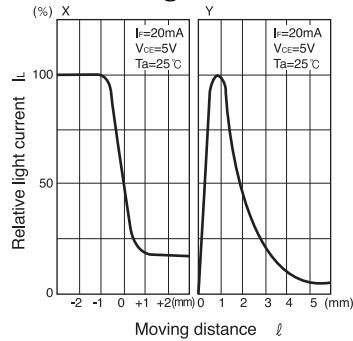
**Dark current Vs.  
Ambient temperature**



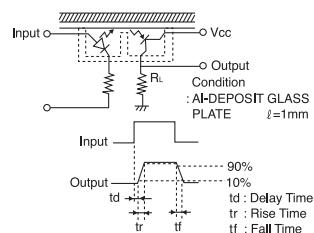
**Switching time Vs.  
Load resistance**



**Relative light current Vs.  
Moving distance**



Switching time measurement circuit



Method of measuring position characteristic

